Declaration and Power of Attorney for Patent Application

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name; I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled

TITLE: Method For Separately Optimizing Thin Gate Dielectric of PMOS and NMOS Transistors within the Same Semiconductor Chip and Device Manufactured Thereby

the spe	ecification of which (c	heck one)					
X	is attached hereto.						
	was filed on as A	Application Serial No	and was amended on _				
		ewed and understand the		- identified specification,			
			which is material to tederal Regulations, §1.5	he patentability of this 56.			
I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:							
	Prior Foreign Application	ation(s): Country	Day/Month/Year	Priority Claimed			
I herel	by claim the benefit	under Title 35, Unit	ed States Code, §120	of any United States			

application(s) listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States application in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose information material to the patentability of this application as defined in Title 37, Code of Federal Regulations, §1.56 which occurred between the filing date of the prior application and the national or PCT international filing date of this application:

Prior U.S. Applications: N/A

Serial No. Filing Date

Status

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

As a named inventor, I hereby appoint the following attorneys and/or agents to prosecute this application and transact all business in the Patent and Trademark Office connected therewith:

Joseph P. Abate,	Registration No. 30,238;	Jay H. Anderson,	Registration No. 38,371;			
Ira D. Blecker,	Registration No. 29,894;	Steven Capella,	Registration No. 33,086;			
James J. Cioffi,	Registration No. 51,564;	Harold H. Huberfeld,	Registration No. 26,665;			
Todd M. C. Li,	Registration No. 45,554;	Anthony N. Magistrale,	Registration No. 35,595;			
Margaret A. Pepper,	Registration No. 45,008;	Eugene I. Shkurko,	Registration No. 36,678;			
H. Daniel Schnurmann,	Registration No. 35,791;	William K. Skladony,	Registration No. 33,787;			
Steven J. Soucar,	Registration No. 32,440;	Tiffany L. Townsend,	Registration No. 43,199;			
all of INTERNATIONAL BUSINESS MACHINES CORPORATION: and						

John E. Hoel, Registration No. 26,279; Christopher A. Hughes, Registration No. 26,914; Joseph C. Redmond, Jr., Registration No. 18,753; all of MORGAN & FINNEGAN, L.L.P.; and

Graham S. Jones, II, Registration No. 20,429.

Send all correspondence to: Graham S. Jones, II

42 Barnard Avenue

Poughkeepsie, New York 12601-5023

Direct Telephone Calls to: Graham S. Jones, II (845) 473-9118

(1) Inventor: Anthony I-Chih Chou

Signature: MMONY Cloy 8/28/0

Residence: 8 Greenhill Drive, Apt. 40C

Fishkill NY 12524

Citizenship: USA

Post Office Address: Same as residence.

Atty. Docket No. FIS920030228US1

(2)	Inventor:	Toshiharu Furukawa	y. Docket 140. F15920030228
	Signature	Tooksush Loubaur	a 9/02/03
	Residence:	9 Oakwood Lane	Date
		Essex Junction, Vermont 05452	
	Citizenship:		
	Post Office	Address: Same as residence	
(3)	Inventor:	Patrick R. Varekamp	
	Signature:_	forda pe Varago	8/28/03 Date
	Residence:	13 Beekman Avenue	2
		Croton on Hudson, New York 10520	
	Citizenship:	USA	
	Post Office A	Address: Same as residence.	
(4)	Inventor:	Jeffrey W. Sleight	
	Signature:		
			Date
	Residence:	129 Keeler Drive	
		Ridgefield, Connecticut 06877	
	Citizenship:	USA	
		ddress: Same as residence.	•
(5)	Inventor:	Akihisa Sekiguchi	
	Signature:		
			Date
	Residence:	250 Hardscrabble Road	
	Citizenship:	Briarcliff Manor, New York 10510 Japan	
Post C		Same as residence.	

(2)	Inventor:	Toshiharu Furukawa	
	Signature:		Data
	Dagidanaa	0 Oalessa d I and	Date
	Residence:	9 Oakwood Lane Essex Junction, Vermont 05452	
	Citizenship:	Japan	
	Post Office A	Address: Same as residence	
(3)	Inventor:	Patrick R. Varekamp	
	Signature:	fatila p Varag	8/28/03 Date
	Residence:	13 Beekman Avenue	Date
	Citizenship: Post Office A	Croton on Hudson, New York 10520 USA Address: Same as residence.	
(4)	Inventor:	Jeffrey W. Sleight	
	Signature:	Allig N. Slife	$\frac{9/2/03}{Date}$
	Residence:	129 Keeler Drive	
		Ridgefield, Connecticut 06877	
	Citizenship:	USA	
	Post Office A	Address: Same as residence.	
(5)	Inventor:	Akihisa Sekiguchi	
	Signature:	a S	$\frac{9/3/2003}{\text{Date}}$
	Residence:	250 Hardscrabble Road	2
		Briarcliff Manor, New York 10510	
	Citizenship:	Japan	

Post Office Address: Same as residence.